

DYNAMIC CHARACTERISTICS

APT100GN120J

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
C_{ies}	Input Capacitance	Capacitance $V_{GE} = 0V, V_{CE} = 25V$ $f = 1 \text{ MHz}$		6500		pF
C_{oes}	Output Capacitance			365		
C_{res}	Reverse Transfer Capacitance			280		
V_{GEP}	Gate-to-Emitter Plateau Voltage	Gate Charge $V_{GE} = 15V$ $V_{CE} = 600V$ $I_C = 100A$		9.5		V
Q_g	Total Gate Charge ^③			540		nC
Q_{ge}	Gate-Emitter Charge			50		
Q_{gc}	Gate-Collector ("Miller") Charge			295		
SSOA	Switching Safe Operating Area	$T_J = 150^\circ C, R_G = 4.3\Omega^{\textcircled{7}}, V_{GE} = 15V, L = 100\mu H, V_{CE} = 1200V$	300			A
$t_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) $V_{CC} = 800V$ $V_{GE} = 15V$ $I_C = 100A$ $R_G = 1.0\Omega^{\textcircled{7}}$ $T_J = +25^\circ C$		50		ns
t_r	Current Rise Time			50		
$t_{d(off)}$	Turn-off Delay Time			615		
t_f	Current Fall Time			105		
E_{on1}	Turn-on Switching Energy ^④			11		mJ
E_{on2}	Turn-on Switching Energy (Diode) ^⑤			15		
E_{off}	Turn-off Switching Energy ^⑥			9.5		
$t_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{CC} = 800V$ $V_{GE} = 15V$ $I_C = 100A$ $R_G = 1.0\Omega^{\textcircled{7}}$ $T_J = +125^\circ C$		50		ns
t_r	Current Rise Time			50		
$t_{d(off)}$	Turn-off Delay Time			725		
t_f	Current Fall Time			210		
E_{on1}	Turn-on Switching Energy ^④			12		mJ
E_{on2}	Turn-on Switching Energy (Diode) ^⑤			22		
E_{off}	Turn-off Switching Energy ^⑥			14		

THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to Case (IGBT)			.28	°C/W
$R_{\theta JC}$	Junction to Case (DIODE)			N/A	
$V_{Isolation}$	RMS Voltage (50-60Hz Sinusoidal Waveform from Terminals to Mounting Base for 1 Min.)	2500			Volts
W_T	Package Weight		1.03		oz
			29.2		gm
Torque	Maximum Terminal & Mounting Torque			10	lb•in
				1.1	N•m

① Repetitive Rating: Pulse width limited by maximum junction temperature.

② For Combi devices, I_{ces} includes both IGBT and FRED leakages

③ See MIL-STD-750 Method 3471.

④ E_{on1} is the clamped inductive turn-on energy of the IGBT only, without the effect of a commutating diode reverse recovery current adding to the IGBT turn-on loss. Tested in inductive switching test circuit shown in figure 21, but with a Silicon Carbide diode.

⑤ E_{on2} is the clamped inductive turn-on energy that includes a commutating diode reverse recovery current in the IGBT turn-on switching loss. (See Figures 21, 22.)

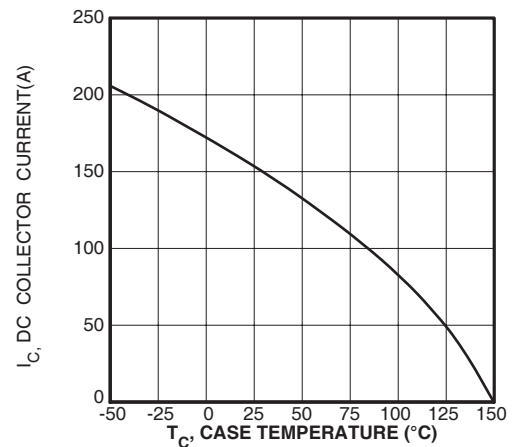
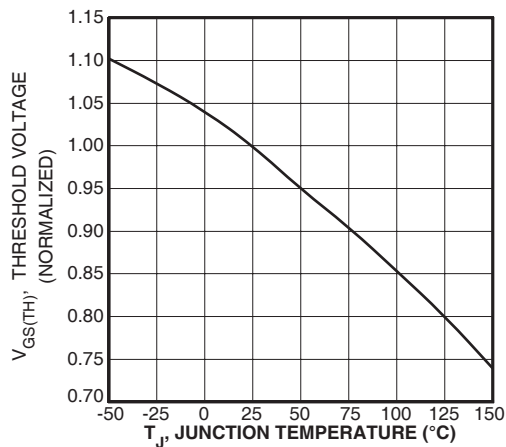
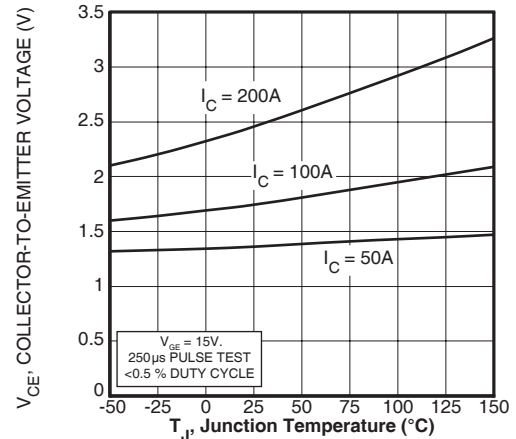
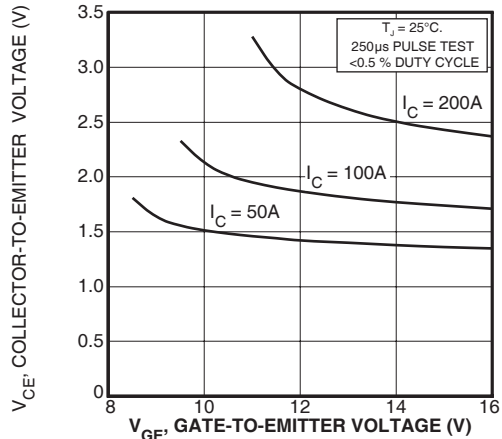
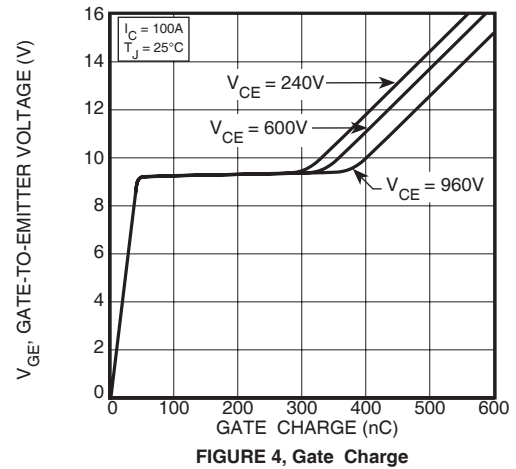
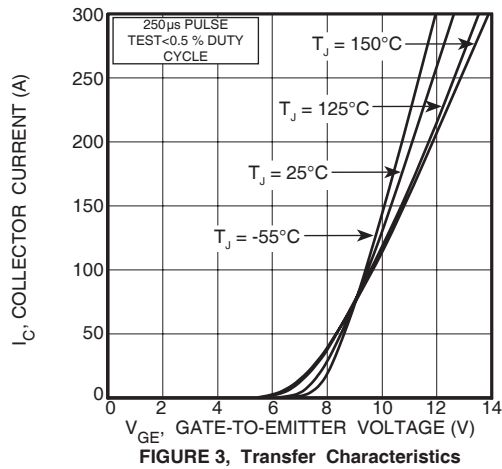
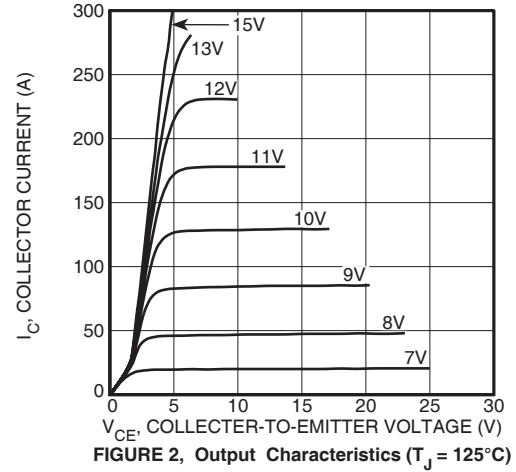
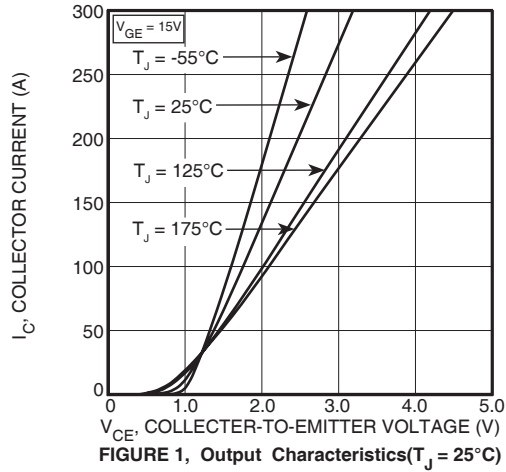
⑥ E_{off} is the clamped inductive turn-off energy measured in accordance with JEDEC standard JESD24-1. (See Figures 21, 23.)

⑦ R_G is external gate resistance, not including $R_{G(int)}$ nor gate driver impedance. (MIC4452)

APT Reserves the right to change, without notice, the specifications and information contained herein.

TYPICAL PERFORMANCE CURVES

APT100GN120J



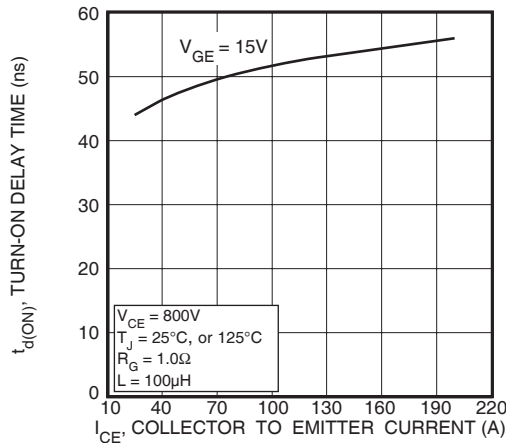


FIGURE 9, Turn-On Delay Time vs Collector Current

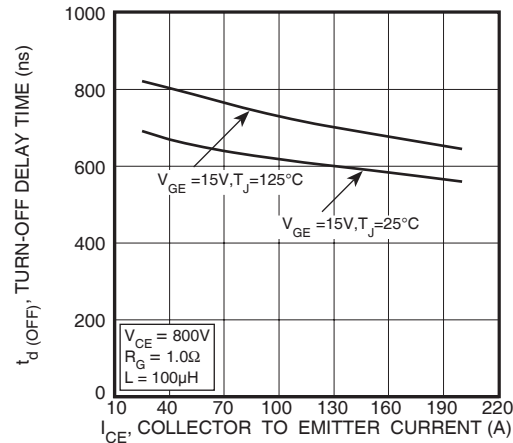


FIGURE 10, Turn-Off Delay Time vs Collector Current

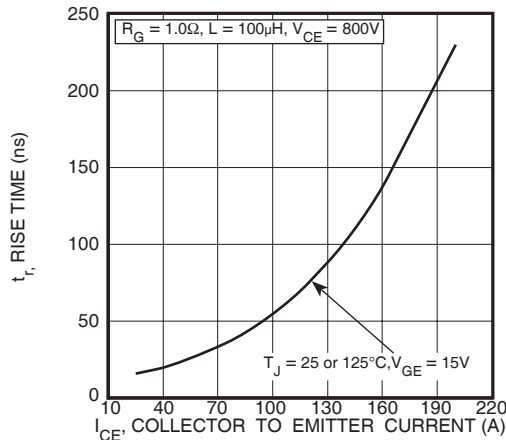


FIGURE 11, Current Rise Time vs Collector Current

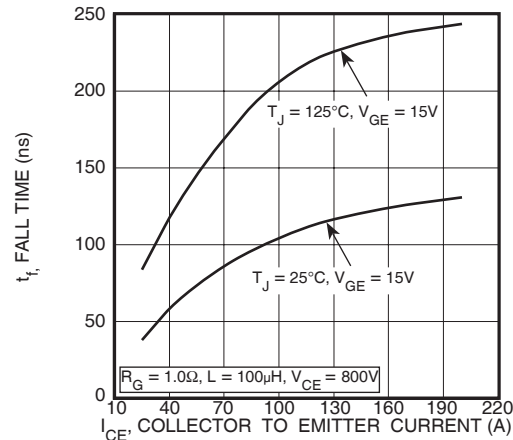


FIGURE 12, Current Fall Time vs Collector Current

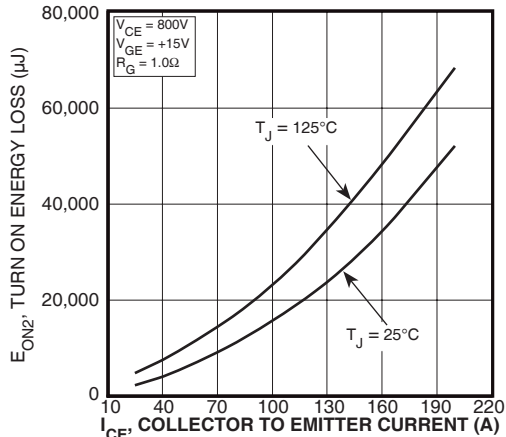


FIGURE 13, Turn-On Energy Loss vs Collector Current

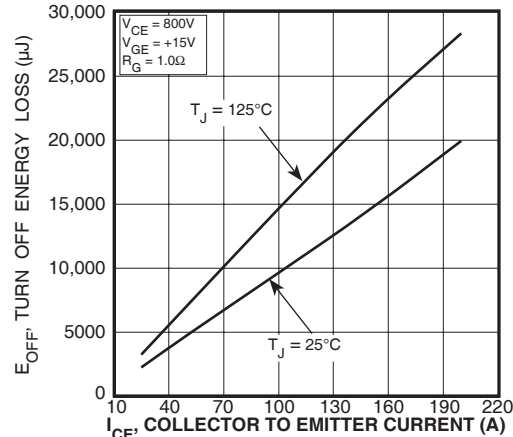


FIGURE 14, Turn Off Energy Loss vs Collector Current

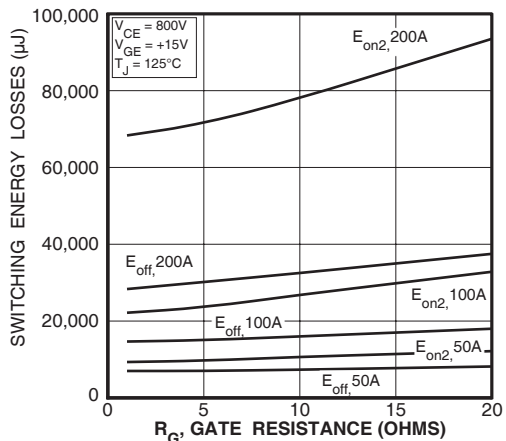


FIGURE 15, Switching Energy Losses vs. Gate Resistance

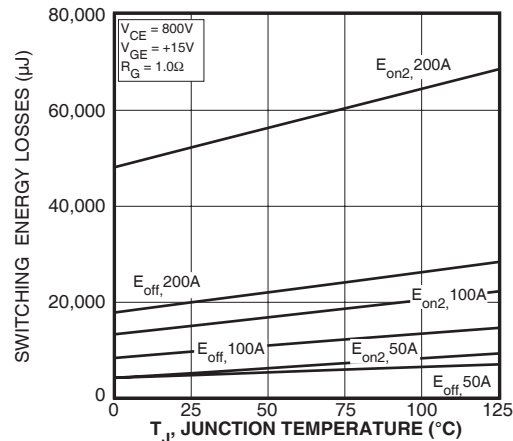


FIGURE 16, Switching Energy Losses vs Junction Temperature

TYPICAL PERFORMANCE CURVES

APT100GN120J

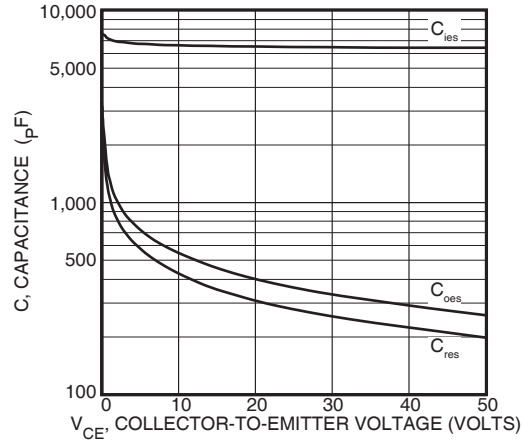


Figure 17, Capacitance vs Collector-To-Emitter Voltage

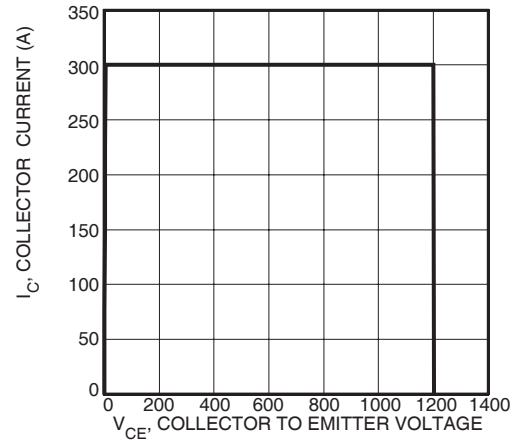


Figure 18, Minimum Switching Safe Operating Area

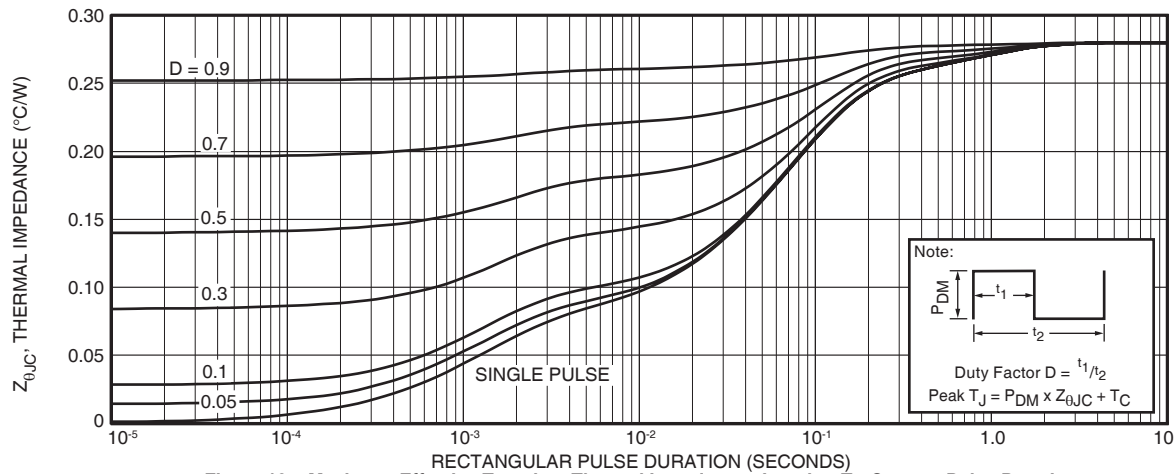


Figure 19a, Maximum Effective Transient Thermal Impedance, Junction-To-Case vs Pulse Duration

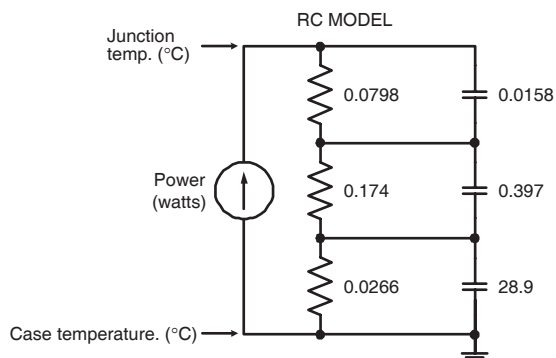


FIGURE 19b, TRANSIENT THERMAL IMPEDANCE MODEL

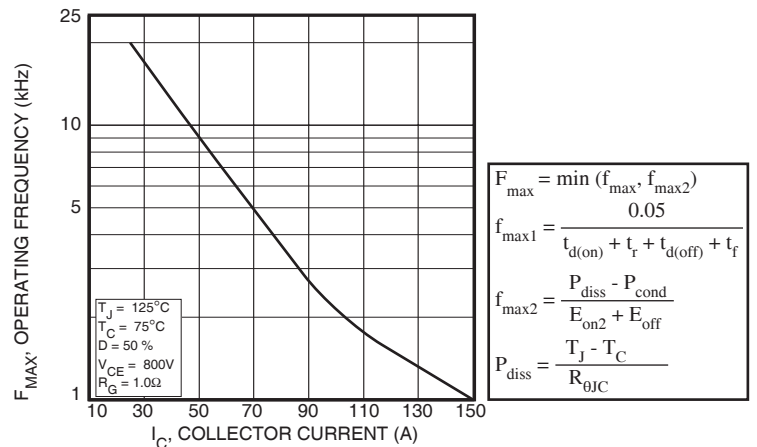


Figure 20, Operating Frequency vs Collector Current

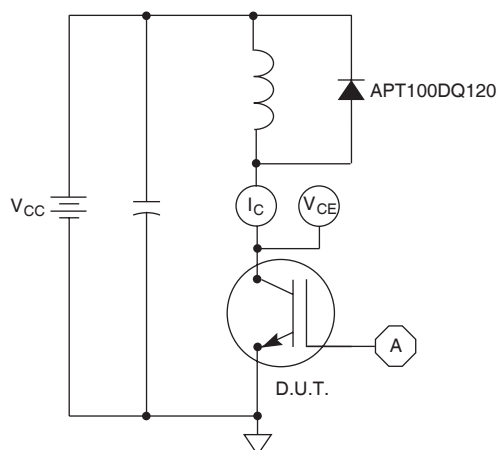


Figure 21, Inductive Switching Test Circuit

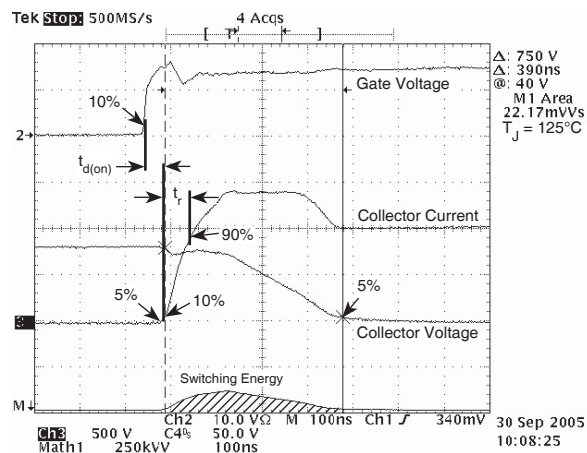


Figure 22, Turn-on Switching Waveforms and Definitions

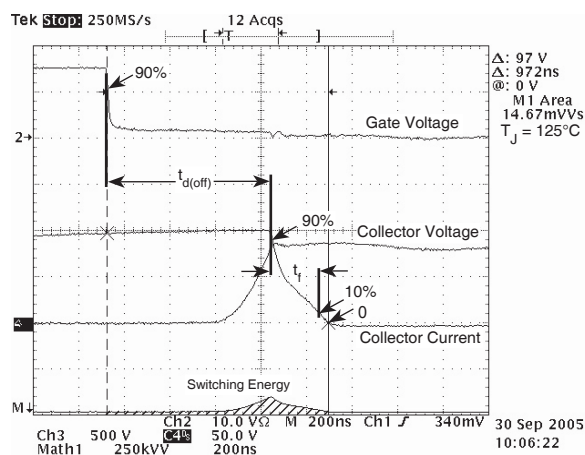
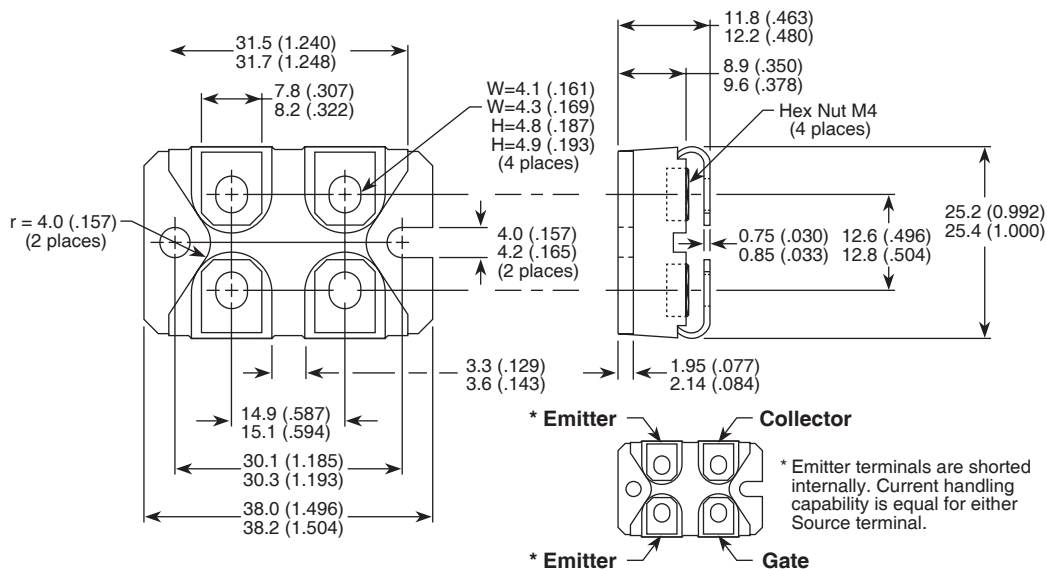


Figure 23, Turn-off Switching Waveforms and Definitions

SOT-227 (ISOTOP®) Package Outline



Dimensions in Millimeters and (Inches)

ISOTOP® is a Registered Trademark of SGS Thomson.